NPN 100mA 50V Digital Transistors (Bias Resistor Built-in Transistors)

Datasheet

Parameter	Value
V _{CC}	50V
I _{C(MAX.)}	100mA
R ₁	10kΩ
R ₂	4.7kΩ

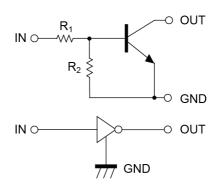
Features

- 1) Built-In Biasing Resistors
- 2) Built-in bias resistors enable the configuration of an inverter circuit without connecting external input resistors (see inner circuit).
- 3) The bias resistors consist of thin-film resistors with complete isolation to allow negative biasing of the input. They also have the advantage of completely eliminating parasitic effects.
- 4) Only the on/off conditions need to be set for operation, making the circuit design easy.
- 5) Complementary PNP Types: DTA114W series
- 6) Lead Free/RoHS Compliant.

DTC114WKA SOT-346(SC-59)

•Inner circuit

Outline



Application

Switching circuit, Inverter circuit, Interface circuit, Driver circuit

Packaging specifications

Part No.	Package	Package size	Taping code	Reel size (mm)	Tape width (mm)	Basic ordering unit.(pcs)	Marking
DTC114WE	EMT3	1616	TL	180	8	3000	84
DTC114WUA	UMT3	2021	T106	180	8	3000	84
DTC114WKA	SMT3	2928	T146	180	8	3000	84

● Absolute maximum ratings (T_a = 25°C)

Parameter			Values	Unit
Supply voltage			50	V
Input voltage			-10 to 30	V
Output current			100	mA
Collector current			100	mA
	DTC114WE		150	
Power dissipation	DTC114WUA	P _D *2	200	mW
	DTC114WKA		200	
Junction temperature		T _j	150	°C
Range of storage temperature		T _{stg}	-55 to +150	°C

● Electrical characteristics (T_a = 25°C)

Downwater	Cymahal	Canditions	Values			Unit	
Parameter	Symbol	Conditions	Min.	Тур.	Max.	Offic	
lanut valtaga	$V_{I(off)}$	V _{CC} = 5V, I _O = 100μA	-	-	0.8	V	
Input voltage	V _{I(on)}	$V_O = 0.3V$, $I_O = 2mA$	3	-	-		
Output voltage	V _{O(on)}	I _O /I _I = 10mA / 0.5mA	-	0.1	0.3	V	
Input current	I _I	V _I = 5V	-	-	0.88	mA	
Output current	I _{O(off)}	V _{CC} = 50V, V _I = 0V	-	-	0.5	μA	
DC current gain	G _I	$V_{O} = 5V, I_{O} = 10mA$	24	-	-	-	
Input resistance	R ₁	-	7	10	13	kΩ	
Resistance ratio	R ₂ /R ₁	-	0.37	0.47	0.57	-	
Transition frequency	f _T *1	V _{CE} = 10V, I _E = -5mA, f = 100MHz	-	250	-	MHz	

^{*1} Characteristics of built-in transistor

^{*2} Each terminal mounted on a reference footprint

● Electrical characteristic curves (T_a =25°C)

Fig.1 Input voltage vs. output current (ON characteristics)

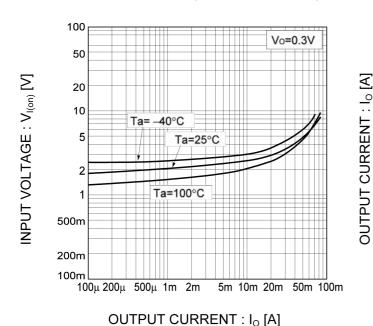


Fig.2 Output current vs. input voltage (OFF characteristics)

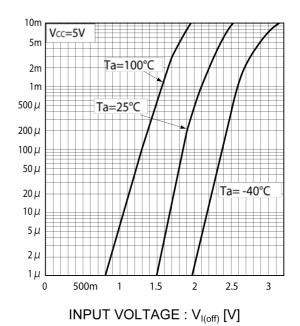


Fig.3 Output current vs. output voltage

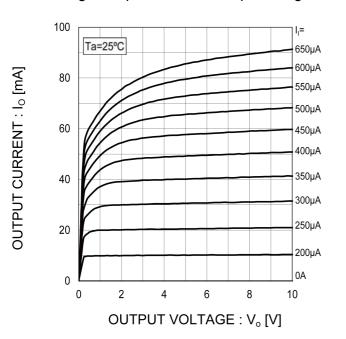
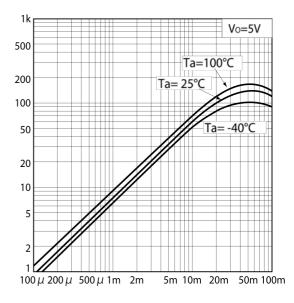


Fig.4 DC current gain vs. output current

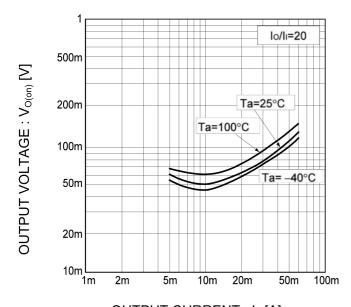


OUTPUT CURRENT: Io [A]

OC CURRENT GAIN: G

● Electrical characteristic curves (T_a =25°C)

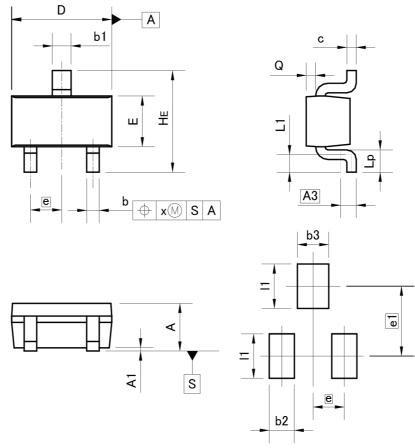
Fig.5 Output voltage vs. output current



OUTPUT CURRENT : Io [A]

Dimensions

EMT3



Pattern of terminal position areas [Not a recommended pattern of soldering pads]

DIM -	MILIM	ETERS	INCHES	
DIM [MIN	MAX	MIN	MAX
Α	0.60	0.80	0.024	0.031
A1	0.00	0.10	0.000	0.004
A3	0.	25	0.0	10
b	0.15	0.30	0.006	0.012
b1	0.25	0.40	0.010	0.016
С	0.10	0.20	0.004	0.008
D	1.50	1.70	0.059	0.067
E	0.70	0.90	0.028	0.035
е	0.	50	0.0	20
HE	1.40	1.80	0.055	0.071
L1	0.10		0.004	
Lp	0.15	550	0.006	77.
Q	0.05	0.25	0.002	0.010
x	— :	0.10	=	0.004

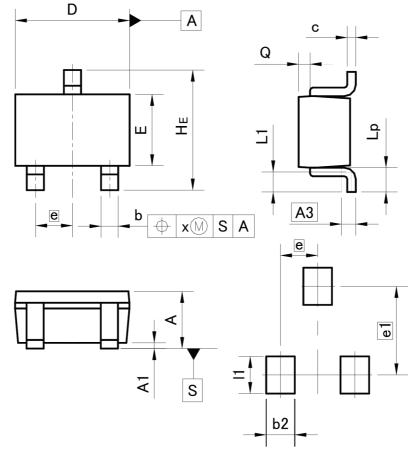
DIM	MILIMETERS		INCHES	
DIM	MIN	MAX	MIN	MAX
b2	17 11	0.40	. 	0.016
b3		0.50	-	0.020
e1	1.	1.10		043
11	#25	0.70	-	0.028

Dimension in mm/inches



Dimensions

UMT3



Pattern of terminal position areas [Not a recommended pattern of soldering pads]

DIM	MILIM	ETERS	INC	HES
DIM	MIN	MAX	MIN	MAX
Α	0.80	1.00	0.031	0.039
A1	0.00	0.10	0.000	0.004
A3	0.3	25	0.0	10
b	0.15	0.30	0.006	0.012
С	0.10	0.20	0.004	0.008
D	1.90	2.10	0.075	0.083
E	1.15	1.35	0.045	0.053
е	0.0	65	0.0	26
HE	2.00	2.20	0.079	0.087
L1	0.20	0.50	0.008	0.020
Lp	0.25	0.55	0.010	0.022
Q	0.10	0.30	0.004	0.012
х	=	0.10	=	0.004

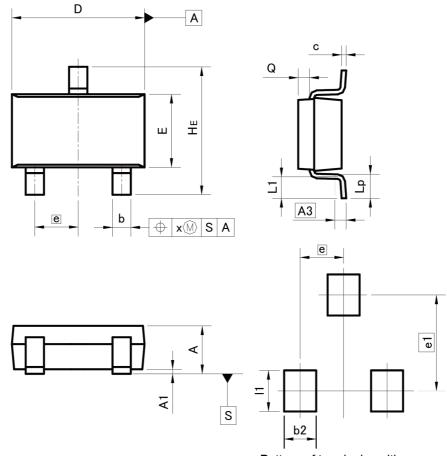
DIM	MILIMETERS		INCHES	
DIM	MIN	MAX	MIN	MAX
b2		0.50		0.020
e1	1.55		0.0	061
11	_	0.65	-	0.026

Dimension in mm/inches



Dimensions

SMT3



Pattern of terminal position areas [Not a recommended pattern of soldering pads]

DIM	MILIMETERS		INCHES	
DIM	MIN	MAX	MIN	MAX
Α	1.00	1.30	0.039	0.051
A1	0.00	0.10	0.000	0.004
A3	0.:	25	0.0	10
b	0.35	0.50	0.014	0.020
С	0.09	0.25	0.004	0.010
D	2.80	3.00	0.110	0.118
E	1.50	1.80	0.059	0.071
е	0.95		0.037	
HE	2.60	3.00	0.102	0.118
L1	0.30	0.60	0.012	0.024
Lp	0.40	0.70	0.016	0.028
Q	0.20	0.30	0.008	0.012
x	(2)	0.10	122	0.004
У	29	0.10	22	0.004
DIM	MILIMETERS		INC	HES
DIM	MIN	MAX	MIN	MAX
b2	=	0.60	:	0.024
e1	2.10		0.0	83

Dimension in mm/inches

11



0.035

0.90

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